

Silicon Carbide Schottky Barrier Diode



Features

- Temperature Independent Switching Behavior
- High Surge Current Capability
- Competitive VF 1.3V at rated current
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

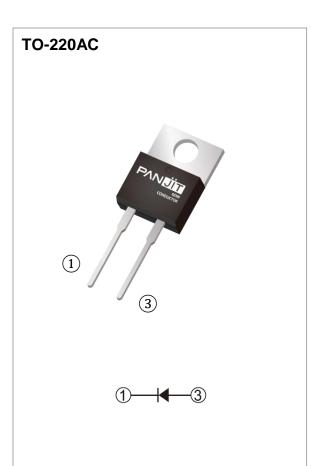
- Case: TO-220AC molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 1.8903 grams

Application

• PFC, UPS, PV Inverter, EV Charging Station, Welder

Maximum Ratings and Thermal Characteristics (Tc = 25 °C unless otherwise specified)

PARAMETE	SYMBOL	LIMIT	UNITS		
Repetitive Peak Reverse Voltage	Vrrm	650	V		
DC Blocking Voltage	V _{DC}	650	V		
Continuous Forward Current	T _C = 160 °C	IF	4	А	
Repetitive Peak Surge Current	$T_{C}=25 ^{\circ}C$, $t_{p}=10ms$		24		
Half Sine Wave, D=0.1	$T_C=125 \circ C$, $t_p =10ms$	IFRM	20	A	
Peak Forward Surge Current	$T_{C}=25 ^{\circ}C$, $t_{p}=10ms$		28	A	
Half Sine Wave	$T_C=125 \circ C$, $t_p =10ms$		24		
Peak Forward Surge Current $t_p = 10us, Pulse$	IFSM	320	A		
Maximum Power Dissipation	P _{total}	65.3	W		
Operating Junction Temperature Rai	TJ	-55~175	°C		
Storage Temperature Range	T _{STG}	-55~175	°C		



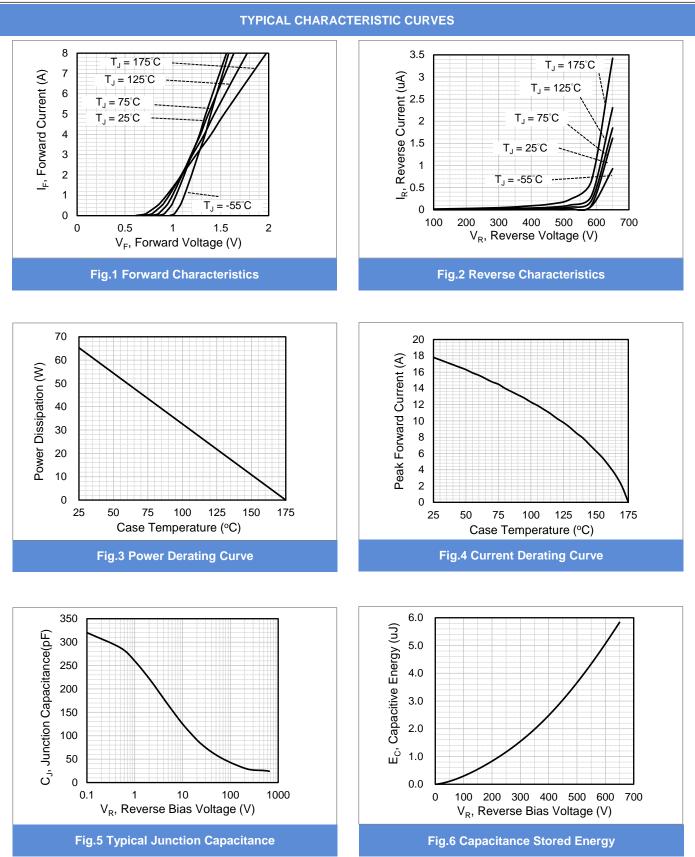


Electrical Characteristics (Tc = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Forward Voltage Drop	VF	I _F = 4 A, T _J = 25 °C	-	1.3	1.6	- V	
		I _F = 4 A, T _J = 175 °C	-	1.4	-		
Reverse Leakage Current	IR	V _R = 650 V, T _J = 25 °C	-	1.6	100	μA	
		V _R = 650 V, T _J = 175 °C	-	3	-	μA	
Total Capacitive Charge	Qc	V _R = 400V	-	16	-	nC	
Total Capacitance	С	V _R = 1V, f = 1MHz	-	260	-	pF	
		V _R = 200V, f = 1MHz	-	30	-	pF	
		V _R = 400V, f = 1MHz	-	26	-	pF	
Capacitance Stored Energy	Ec	V _R = 400V	-	2.4	-	μJ	
Thermal Resistance	Rejc		-	2.3	-	°C/W	



PCDP0465GB

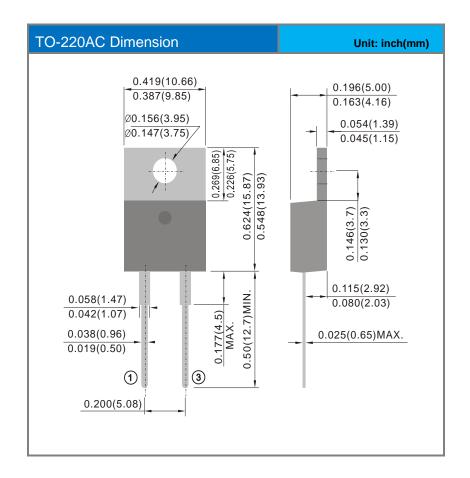




Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PCDP0465GB	TO-220AC	50pcs / Tube	CDP0465GB

Packaging Information





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